



Welcome to **E-XFL.COM**

Understanding <u>Embedded - FPGAs (Field Programmable Gate Array)</u>

Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

Applications of Embedded - FPGAs

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications.

| Details | |
|--------------------------------|---|
| Product Status | Obsolete |
| Number of LABs/CLBs | 225400 |
| Number of Logic Elements/Cells | 597000 |
| Total RAM Bits | 53248000 |
| Number of I/O | 432 |
| Number of Gates | - |
| Voltage - Supply | 0.82V ~ 0.88V |
| Mounting Type | Surface Mount |
| Operating Temperature | 0°C ~ 85°C (TJ) |
| Package / Case | 1517-FBGA (40x40) |
| Supplier Device Package | 1517-FBGA (40x40) |
| Purchase URL | https://www.e-xfl.com/product-detail/intel/5sgxeb6r3f40c3 |

Email: info@E-XFL.COM

Address: Room A, 16/F, Full Win Commercial Centre, 573 Nathan Road, Mongkok, Hong Kong

Page 2 Electrical Characteristics

Table 1. Stratix V GX and GS Commercial and Industrial Speed Grade Offering (1), (2), (3) (Part 2 of 2)

| Transceiver Speed | | | | Core Spe | ed Grade | | | |
|--------------------------|----|---------|-----|----------|----------|---------|--------------------|-----|
| Grade | C1 | C2, C2L | C3 | C4 | 12, 12L | 13, 13L | I3YY | 14 |
| 3 GX channel—8.5 Gbps | _ | Yes | Yes | Yes | _ | Yes | Yes ⁽⁴⁾ | Yes |

Notes to Table 1:

- (1) C = Commercial temperature grade; I = Industrial temperature grade.
- (2) Lower number refers to faster speed grade.
- (3) C2L, I2L, and I3L speed grades are for low-power devices.
- (4) I3YY speed grades can achieve up to 10.3125 Gbps.

Table 2 lists the industrial and commercial speed grades for the Stratix V GT devices.

Table 2. Stratix V GT Commercial and Industrial Speed Grade Offering (1), (2)

| Transacius Crad Crado | Core Speed Grade | | | | | | |
|--|------------------|-----|-----|-----|--|--|--|
| Transceiver Speed Grade | C1 | C2 | 12 | 13 | | | |
| 2 GX channel—12.5 Gbps GT channel—28.05 Gbps | Yes | Yes | _ | _ | | | |
| 3 GX channel—12.5 Gbps GT channel—25.78 Gbps | Yes | Yes | Yes | Yes | | | |

Notes to Table 2:

- (1) C = Commercial temperature grade; I = Industrial temperature grade.
- (2) Lower number refers to faster speed grade.

Absolute Maximum Ratings

Absolute maximum ratings define the maximum operating conditions for Stratix V devices. The values are based on experiments conducted with the devices and theoretical modeling of breakdown and damage mechanisms. The functional operation of the device is not implied for these conditions.



Conditions other than those listed in Table 3 may cause permanent damage to the device. Additionally, device operation at the absolute maximum ratings for extended periods of time may have adverse effects on the device.

Table 3. Absolute Maximum Ratings for Stratix V Devices (Part 1 of 2)

| Symbol | Description | Minimum | Maximum | Unit |
|---------------------|--|---------|---------|------|
| V _{CC} | Power supply for core voltage and periphery circuitry | -0.5 | 1.35 | V |
| V _{CCPT} | Power supply for programmable power technology | -0.5 | 1.8 | V |
| V _{CCPGM} | Power supply for configuration pins | -0.5 | 3.9 | V |
| V _{CC_AUX} | Auxiliary supply for the programmable power technology | -0.5 | 3.4 | V |
| V _{CCBAT} | Battery back-up power supply for design security volatile key register | -0.5 | 3.9 | V |
| V _{CCPD} | I/O pre-driver power supply | -0.5 | 3.9 | V |
| V _{CCIO} | I/O power supply | -0.5 | 3.9 | V |

Electrical Characteristics Page 3

Table 3. Absolute Maximum Ratings for Stratix V Devices (Part 2 of 2)

| Symbol | Description | Minimum | Maximum | Unit |
|-----------------------|--------------------------------|---------|---------|------|
| V _{CCD_FPLL} | PLL digital power supply | -0.5 | 1.8 | V |
| V _{CCA_FPLL} | PLL analog power supply | -0.5 | 3.4 | V |
| V _I | DC input voltage | -0.5 | 3.8 | V |
| T _J | Operating junction temperature | -55 | 125 | °C |
| T _{STG} | Storage temperature (No bias) | -65 | 150 | °C |
| I _{OUT} | DC output current per pin | -25 | 40 | mA |

Table 4 lists the absolute conditions for the transceiver power supply for Stratix V GX, GS, and GT devices.

Table 4. Transceiver Power Supply Absolute Conditions for Stratix V GX, GS, and GT Devices

| Symbol | Description | Devices | Minimum | Maximum | Unit |
|-----------------------|--|------------|---------|---------|------|
| V _{CCA_GXBL} | Transceiver channel PLL power supply (left side) | GX, GS, GT | -0.5 | 3.75 | V |
| V _{CCA_GXBR} | Transceiver channel PLL power supply (right side) | GX, GS | -0.5 | 3.75 | V |
| V _{CCA_GTBR} | Transceiver channel PLL power supply (right side) | GT | -0.5 | 3.75 | V |
| V _{CCHIP_L} | Transceiver hard IP power supply (left side) | GX, GS, GT | -0.5 | 1.35 | V |
| V _{CCHIP_R} | Transceiver hard IP power supply (right side) | GX, GS, GT | -0.5 | 1.35 | V |
| V _{CCHSSI_L} | Transceiver PCS power supply (left side) | GX, GS, GT | -0.5 | 1.35 | V |
| V _{CCHSSI_R} | Transceiver PCS power supply (right side) | GX, GS, GT | -0.5 | 1.35 | V |
| V _{CCR_GXBL} | Receiver analog power supply (left side) | GX, GS, GT | -0.5 | 1.35 | V |
| V _{CCR_GXBR} | Receiver analog power supply (right side) | GX, GS, GT | -0.5 | 1.35 | V |
| V _{CCR_GTBR} | Receiver analog power supply for GT channels (right side) | GT | -0.5 | 1.35 | V |
| V _{CCT_GXBL} | Transmitter analog power supply (left side) | GX, GS, GT | -0.5 | 1.35 | V |
| V _{CCT_GXBR} | Transmitter analog power supply (right side) | GX, GS, GT | -0.5 | 1.35 | V |
| V _{CCT_GTBR} | Transmitter analog power supply for GT channels (right side) | GT | -0.5 | 1.35 | V |
| V _{CCL_GTBR} | Transmitter clock network power supply (right side) | GT | -0.5 | 1.35 | V |
| V _{CCH_GXBL} | Transmitter output buffer power supply (left side) | GX, GS, GT | -0.5 | 1.8 | V |
| V _{CCH_GXBR} | Transmitter output buffer power supply (right side) | GX, GS, GT | -0.5 | 1.8 | V |

Maximum Allowed Overshoot and Undershoot Voltage

During transitions, input signals may overshoot to the voltage shown in Table 5 and undershoot to -2.0 V for input currents less than 100 mA and periods shorter than 20 ns.

Page 6 Electrical Characteristics

Table 6. Recommended Operating Conditions for Stratix V Devices (Part 2 of 2)

| Symbol | Description | Condition | Min ⁽⁴⁾ | Тур | Max ⁽⁴⁾ | Unit |
|-------------------|------------------------|--------------|--------------------|-----|--------------------|------|
| t _{RAMP} | Power cupply ramp time | Standard POR | 200 μs | _ | 100 ms | _ |
| | Power supply ramp time | Fast POR | 200 μs | _ | 4 ms | _ |

Notes to Table 6:

- (1) V_{CCPD} must be 2.5 V when V_{CCIO} is 2.5, 1.8, 1.5, 1.35, 1.25 or 1.2 V. V_{CCPD} must be 3.0 V when V_{CCIO} is 3.0 V.
- (2) If you do not use the design security feature in Stratix V devices, connect V_{CCBAT} to a 1.2- to 3.0-V power supply. Stratix V power-on-reset (POR) circuitry monitors V_{CCBAT}. Stratix V devices will not exit POR if V_{CCBAT} stays at logic low.
- (3) C2L and I2L can also be run at 0.90 V for legacy boards that were designed for the C2 and I2 speed grades.
- (4) The power supply value describes the budget for the DC (static) power supply tolerance and does not include the dynamic tolerance requirements. Refer to the PDN tool for the additional budget for the dynamic tolerance requirements.

Table 7 lists the transceiver power supply recommended operating conditions for Stratix V GX, GS, and GT devices.

Table 7. Recommended Transceiver Power Supply Operating Conditions for Stratix V GX, GS, and GT Devices (Part 1 of 2)

| Symbol | Description | Devices | Minimum ⁽⁴⁾ | Typical | Maximum ⁽⁴⁾ | Unit |
|------------------------|---|------------|------------------------|---------|------------------------|------|
| V _{CCA_GXBL} | Transceiver channel PLL power supply (left | GX, GS, GT | 2.85 | 3.0 | 3.15 | V |
| (1), (3) | side) | ७४, ७७, ७१ | 2.375 | 2.5 | 2.625 | V |
| V _{CCA_GXBR} | Transceiver channel PLL power supply (right | GX, GS | 2.85 | 3.0 | 3.15 | V |
| $(1), (\overline{3})$ | side) | GA, GS | 2.375 | 2.5 | 2.625 | V |
| V _{CCA_GTBR} | Transceiver channel PLL power supply (right side) | GT | 2.85 | 3.0 | 3.15 | V |
| | Transceiver hard IP power supply (left side; C1, C2, I2, and I3YY speed grades) | GX, GS, GT | 0.87 | 0.9 | 0.93 | V |
| V _{CCHIP_L} | Transceiver hard IP power supply (left side; C2L, C3, C4, I2L, I3, I3L, and I4 speed grades) | GX, GS, GT | 0.82 | 0.85 | 0.88 | V |
| V _{CCHIP_R} | Transceiver hard IP power supply (right side; C1, C2, I2, and I3YY speed grades) | GX, GS, GT | 0.87 | 0.9 | 0.93 | V |
| | Transceiver hard IP power supply (right side; C2L, C3, C4, I2L, I3, I3L, and I4 speed grades) | GX, GS, GT | 0.82 | 0.85 | 0.88 | V |
| | Transceiver PCS power supply (left side; C1, C2, I2, and I3YY speed grades) | GX, GS, GT | 0.87 | 0.9 | 0.93 | V |
| V _{CCHSSI_L} | Transceiver PCS power supply (left side; C2L, C3, C4, I2L, I3, I3L, and I4 speed grades) | GX, GS, GT | 0.82 | 0.85 | 0.88 | V |
| | Transceiver PCS power supply (right side; C1, C2, I2, and I3YY speed grades) | GX, GS, GT | 0.87 | 0.9 | 0.93 | V |
| $V_{\text{CCHSSI_R}}$ | Transceiver PCS power supply (right side; C2L, C3, C4, I2L, I3, I3L, and I4 speed grades) | GX, GS, GT | 0.82 | 0.85 | 0.88 | V |
| | | | 0.82 | 0.85 | 0.88 | V |
| V _{CCR_GXBL} | Receiver analog power supply (left side) | GX, GS, GT | 0.87 | 0.90 | 0.93 | |
| (2) | Treceiver arialog power supply (left side) | | 0.97 | 1.0 | 1.03 | |
| | | | 1.03 | 1.05 | 1.07 | |

Electrical Characteristics Page 9

I/O Pin Leakage Current

Table 9 lists the Stratix V I/O pin leakage current specifications.

Table 9. I/O Pin Leakage Current for Stratix V Devices (1)

| Symbol | Description | Conditions | Min | Тур | Max | Unit |
|-----------------|--------------------|--|-----|-----|-----|------|
| I _I | Input pin | $V_I = 0 V to V_{CCIOMAX}$ | -30 | _ | 30 | μΑ |
| I _{OZ} | Tri-stated I/O pin | $V_0 = 0 V \text{ to } V_{\text{CCIOMAX}}$ | -30 | | 30 | μΑ |

Note to Table 9:

(1) If $V_0 = V_{CCIO}$ to $V_{CCIOMax}$, 100 μA of leakage current per I/O is expected.

Bus Hold Specifications

Table 10 lists the Stratix V device family bus hold specifications.

Table 10. Bus Hold Parameters for Stratix V Devices

| | | | V _{CCIO} | | | | | | | | | | |
|-------------------------------|-------------------|--|-------------------|------|-------|------|-------|------|-------|------|-------|------|------|
| Parameter | Symbol | Conditions | 1.2 | 2 V | 1.9 | 5 V | 1.8 | B V | 2. | 5 V | 3.0 | V | Unit |
| | | | Min | Max | Min | Max | Min | Max | Min | Max | Min | Max | |
| Low sustaining current | I _{SUSL} | V _{IN} > V _{IL} (maximum) | 22.5 | _ | 25.0 | _ | 30.0 | _ | 50.0 | _ | 70.0 | _ | μА |
| High sustaining current | I _{SUSH} | V _{IN} < V _{IH} (minimum) | -22.5 | _ | -25.0 | _ | -30.0 | _ | -50.0 | | -70.0 | | μА |
| Low overdrive current | I _{ODL} | 0V < V _{IN} < V _{CCIO} | _ | 120 | _ | 160 | _ | 200 | _ | 300 | _ | 500 | μА |
| High overdrive current | I _{ODH} | 0V < V _{IN} < V _{CCIO} | _ | -120 | _ | -160 | _ | -200 | _ | -300 | _ | -500 | μА |
| Bus-hold trip point | V_{TRIP} | _ | 0.45 | 0.95 | 0.50 | 1.00 | 0.68 | 1.07 | 0.70 | 1.70 | 0.80 | 2.00 | V |

On-Chip Termination (OCT) Specifications

If you enable OCT calibration, calibration is automatically performed at power-up for I/Os connected to the calibration block. Table 11 lists the Stratix V OCT termination calibration accuracy specifications.

Table 11. OCT Calibration Accuracy Specifications for Stratix V Devices (1) (Part 1 of 2)

| | | | Calibration Accuracy | | | | |
|---------------------|---|--|----------------------|-------|----------------|-------|------|
| Symbol | Description | Conditions | C 1 | C2,I2 | C3,I3, I3YY | C4,I4 | Unit |
| 25-Ω R _S | Internal series termination with calibration (25- Ω setting) | V _{CCIO} = 3.0, 2.5, 1.8, 1.5, 1.2 V | ±15 | ±15 | ±15 | ±15 | % |

Page 12 Electrical Characteristics

Table 13. OCT Variation after Power-Up Calibration for Stratix V Devices (Part 2 of 2) (1)

| Symbol | Description | V _{CCIO} (V) | Typical | Unit |
|--------|--|-----------------------|---------|------|
| | | 3.0 | 0.189 | |
| | OCT variation with temperature without recalibration | 2.5 | 0.208 | %/°C |
| dR/dT | | 1.8 | 0.266 | |
| | | 1.5 | 0.273 | 1 |
| | | 1.2 | 0.317 | |

Note to Table 13:

(1) Valid for a V_{CCIO} range of $\pm 5\%$ and a temperature range of 0° to $85^\circ\text{C}.$

Pin Capacitance

Table 14 lists the Stratix V device family pin capacitance.

Table 14. Pin Capacitance for Stratix V Devices

| Symbol | Description | Value | Unit |
|--------------------|--|-------|------|
| C _{IOTB} | Input capacitance on the top and bottom I/O pins | 6 | pF |
| C _{IOLR} | Input capacitance on the left and right I/O pins | 6 | pF |
| C _{OUTFB} | Input capacitance on dual-purpose clock output and feedback pins | 6 | pF |

Hot Socketing

Table 15 lists the hot socketing specifications for Stratix V devices.

Table 15. Hot Socketing Specifications for Stratix V Devices

| Symbol | Description | Maximum |
|---------------------------|--|---------------------|
| I _{IOPIN (DC)} | DC current per I/O pin | 300 μΑ |
| I _{IOPIN (AC)} | AC current per I/O pin | 8 mA ⁽¹⁾ |
| I _{XCVR-TX (DC)} | DC current per transceiver transmitter pin | 100 mA |
| I _{XCVR-RX (DC)} | DC current per transceiver receiver pin | 50 mA |

Note to Table 15:

(1) The I/O ramp rate is 10 ns or more. For ramp rates faster than 10 ns, $|I_{IOPIN}| = C dv/dt$, in which C is the I/O pin capacitance and dv/dt is the slew rate.

Electrical Characteristics Page 15

Table 19. Single-Ended SSTL, HSTL, and HSUL I/O Standards Signal Specifications for Stratix V Devices (Part 2 of 2)

| I/O Standard | V _{IL(D(} | ; ₎ (V) | V _{IH(D} | _{C)} (V) | V _{IL(AC)} (V) | V _{IH(AC)} (V) | V _{OL} (V) | V _{OH} (V) | I _{ol} (mA) | l _{oh} |
|---------------------|--------------------|---------------------------|-------------------------|--------------------------|----------------------------|-------------------------|----------------------------|----------------------------|------------------------|-----------------|
| i/O Stanuaru | Min | Max | Min | Max | Max | Min | Max | Min | I _{OI} (IIIA) | (mA) |
| HSTL-18 Class I | _ | V _{REF} – 0.1 | V _{REF} + 0.1 | _ | V _{REF} - 0.2 | V _{REF} + 0.2 | 0.4 | V _{CCIO} – 0.4 | 8 | -8 |
| HSTL-18 Class II | _ | V _{REF} – 0.1 | V _{REF} + 0.1 | _ | V _{REF} - 0.2 | V _{REF} + 0.2 | 0.4 | V _{CCIO} – 0.4 | 16 | -16 |
| HSTL-15 Class I | _ | V _{REF} – 0.1 | V _{REF} + 0.1 | _ | V _{REF} - 0.2 | V _{REF} + 0.2 | 0.4 | V _{CCIO} – 0.4 | 8 | -8 |
| HSTL-15 Class II | _ | V _{REF} – 0.1 | V _{REF} + 0.1 | _ | V _{REF} - 0.2 | V _{REF} + 0.2 | 0.4 | V _{CCIO} – 0.4 | 16 | -16 |
| HSTL-12 Class I | -0.15 | V _{REF} – 0.08 | V _{REF} + 0.08 | V _{CCIO} + 0.15 | V _{REF} – 0.15 | V _{REF} + 0.15 | 0.25* V _{CCIO} | 0.75* V _{CCIO} | 8 | -8 |
| HSTL-12 Class II | -0.15 | V _{REF} – 0.08 | V _{REF} + 0.08 | V _{CCIO} + 0.15 | V _{REF} – 0.15 | V _{REF} + 0.15 | 0.25* V _{CCIO} | 0.75* V _{CCIO} | 16 | -16 |
| HSUL-12 | _ | V _{REF} – 0.13 | V _{REF} + 0.13 | _ | V _{REF} – 0.22 | V _{REF} + 0.22 | 0.1* V _{CCIO} | 0.9* V _{CCIO} | _ | |

Table 20. Differential SSTL I/O Standards for Stratix V Devices

| I/O Standard | | V _{CCIO} (V) | | V _{SWIN} | _{G(DC)} (V) | | V _{X(AC)} (V) | | V _{SWING(AC)} (V) | |
|-------------------------|-------|-----------------------|-------|-------------------|-------------------------|------------------------------|------------------------|------------------------------|--|---|
| I/O Standard | Min | Тур | Max | Min | Max | Min | Тур | Max | Min | Max |
| SSTL-2 Class I, II | 2.375 | 2.5 | 2.625 | 0.3 | V _{CCIO} + 0.6 | V _{CCIO} /2 – 0.2 | _ | V _{CCIO} /2 + 0.2 | 0.62 | V _{CCIO} + 0.6 |
| SSTL-18 Class I, II | 1.71 | 1.8 | 1.89 | 0.25 | V _{CCIO} + 0.6 | V _{CCIO} /2 – 0.175 | _ | V _{CCIO} /2 + 0.175 | 0.5 | V _{CCIO} + 0.6 |
| SSTL-15 Class I, II | 1.425 | 1.5 | 1.575 | 0.2 | (1) | V _{CCIO} /2 – 0.15 | _ | V _{CCIO} /2 + 0.15 | 0.35 | _ |
| SSTL-135 Class I, II | 1.283 | 1.35 | 1.45 | 0.2 | (1) | V _{CCIO} /2 – 0.15 | V _{CCIO} /2 | V _{CCIO} /2 + 0.15 | 2(V _{IH(AC)} - V _{REF}) | 2(V _{IL(AC)} - V _{REF}) |
| SSTL-125 Class I, II | 1.19 | 1.25 | 1.31 | 0.18 | (1) | V _{CCIO} /2 – 0.15 | V _{CCIO} /2 | V _{CCIO} /2 + 0.15 | 2(V _{IH(AC)} - V _{REF}) | _ |
| SSTL-12 Class I, II | 1.14 | 1.2 | 1.26 | 0.18 | _ | V _{REF} -0.15 | V _{CCIO} /2 | V _{REF} + 0.15 | -0.30 | 0.30 |

Note to Table 20:

Table 21. Differential HSTL and HSUL I/O Standards for Stratix V Devices (Part 1 of 2)

| I/O | | V _{CCIO} (V) | | V _{DIF(} | _{DC)} (V) | $V_{X(AC)}(V)$ $V_{CM(DC)}(V)$ | | $V_{X(AC)}(V)$ $V_{CM(DC)}(V)$ $V_{DIF(AC)}(V)$ | | ^(C) (V) | | | |
|------------------------|-------|-----------------------|-------|-------------------|--------------------|--------------------------------|-----|---|------|-----------------------------|------|-----|-----|
| Standard | Min | Тур | Max | Min | Max | Min | Тур | Max | Min | Тур | Max | Min | Max |
| HSTL-18 Class I, II | 1.71 | 1.8 | 1.89 | 0.2 | _ | 0.78 | _ | 1.12 | 0.78 | _ | 1.12 | 0.4 | _ |
| HSTL-15 Class I, II | 1.425 | 1.5 | 1.575 | 0.2 | | 0.68 | _ | 0.9 | 0.68 | | 0.9 | 0.4 | _ |

⁽¹⁾ The maximum value for $V_{SWING(DC)}$ is not defined. However, each single-ended signal needs to be within the respective single-ended limits $(V_{IH(DC)})$ and $V_{IL(DC)})$.

Page 18 Switching Characteristics

Switching Characteristics

This section provides performance characteristics of the Stratix V core and periphery blocks.

These characteristics can be designated as Preliminary or Final.

- Preliminary characteristics are created using simulation results, process data, and other known parameters. The title of these tables show the designation as "Preliminary."
- Final numbers are based on actual silicon characterization and testing. The numbers reflect the actual performance of the device under worst-case silicon process, voltage, and junction temperature conditions. There are no designations on finalized tables.

Transceiver Performance Specifications

This section describes transceiver performance specifications.

Table 23 lists the Stratix V GX and GS transceiver specifications.

Table 23. Transceiver Specifications for Stratix V GX and GS Devices (1) (Part 1 of 7)

| Symbol/ | Conditions | Trai | nsceive Grade | r Speed 1 | Transceiver Speed Grade 2 | | | Transceiver Speed Grade 3 | | | Unit |
|--|---|-------|------------------|--------------|------------------------------|-------|---------------------|------------------------------|---------|------------|----------|
| Description | | Min | Тур | Max | Min | Тур | Max | Min | Тур | Max | |
| Reference Clock | | | | | | | | | | | |
| Supported I/O Standards | Dedicated reference clock pin | 1.2-V | PCML, | 1.4-V PCM | L, 1.5-V | PCML, | , 2.5-V PCN HCSL | 1L, Diffe | rential | LVPECL, L\ | /DS, and |
| RX reference clock pin 1.4-V PCML, 1.5-V PCML, 2.5-V PCML, LVPECL, and LVDS | | | | | | | | | | | |
| Input Reference Clock Frequency (CMU PLL) (8) | _ | 40 | _ | 710 | 40 | _ | 710 | 40 | _ | 710 | MHz |
| Input Reference Clock Frequency (ATX PLL) (8) | _ | 100 | _ | 710 | 100 | _ | 710 | 100 | _ | 710 | MHz |
| Rise time | Measure at ±60 mV of differential signal ⁽²⁶⁾ | _ | _ | 400 | _ | _ | 400 | _ | _ | 400 | ne |
| Fall time | Measure at ±60 mV of differential signal ⁽²⁶⁾ | _ | _ | 400 | _ | _ | 400 | _ | _ | 400 | ps |
| Duty cycle | _ | 45 | | 55 | 45 | _ | 55 | 45 | | 55 | % |
| Spread-spectrum modulating clock frequency | PCI Express® (PCIe®) | 30 | _ | 33 | 30 | _ | 33 | 30 | _ | 33 | kHz |

Table 23. Transceiver Specifications for Stratix V GX and GS Devices (1) (Part 6 of 7)

| Symbol/ | Conditions | Trai | nsceive Grade | r Speed e 1 | Trar | sceive Grade | r Speed 2 | Tran | sceive Grade | er Speed e 3 | Unit |
|---|--|------|------------------|-------------------------------|------|-----------------|-------------------------------|------|-----------------|-------------------------------|------|
| Description | | Min | Тур | Max | Min | Тур | Max | Min | Тур | Max | |
| Inter-transceiver block transmitter channel-to- channel skew | xN PMA bonded mode | ı | ı | 500 | _ | ı | 500 | _ | _ | 500 | ps |
| CMU PLL | | | | | | | | | | | |
| Supported Data Range | _ | 600 | _ | 12500 | 600 | _ | 12500 | 600 | _ | 8500/ 10312.5 (24) | Mbps |
| t _{pll_powerdown} (15) | _ | 1 | _ | _ | 1 | _ | _ | 1 | _ | _ | μs |
| t _{pll_lock} (16) | _ | _ | _ | 10 | _ | _ | 10 | _ | _ | 10 | μs |
| ATX PLL | | | | | | | | | | | |
| | VCO post-divider L=2 | 8000 | | 14100 | 8000 | | 12500 | 8000 | _ | 8500/ 10312.5 (24) | Mbps |
| Currented Date | L=4 | 4000 | _ | 7050 | 4000 | _ | 6600 | 4000 | _ | 6600 | Mbps |
| Supported Data Rate Range | L=8 | 2000 | _ | 3525 | 2000 | _ | 3300 | 2000 | _ | 3300 | Mbps |
| S | L=8, Local/Central Clock Divider =2 | 1000 | _ | 1762.5 | 1000 | _ | 1762.5 | 1000 | _ | 1762.5 | Mbps |
| t _{pll_powerdown} (15) | _ | 1 | _ | _ | 1 | _ | _ | 1 | _ | _ | μs |
| t _{pll_lock} (16) | _ | | _ | 10 | _ | _ | 10 | _ | _ | 10 | μs |
| fPLL | | | | | | | | | | | |
| Supported Data Range | _ | 600 | _ | 3250/ 3125 ⁽²⁵⁾ | 600 | _ | 3250/ 3125 ⁽²⁵⁾ | 600 | _ | 3250/ 3125 ⁽²⁵⁾ | Mbps |
| t _{pll_powerdown} (15) | _ | 1 | _ | | 1 | _ | | 1 | | | μs |

Table 24 shows the maximum transmitter data rate for the clock network.

Table 24. Clock Network Maximum Data Rate Transmitter Specifications (1)

| | | ATX PLL | | | CMU PLL (2) |) | | fPLL | |
|-----------------------------------|----------------------------------|--------------------------|--|----------------------------------|--------------------------|-------------------------|----------------------------------|--------------------------|-------------------------|
| Clock Network | Non- bonded Mode (Gbps) | Bonded Mode (Gbps) | Channel Span | Non- bonded Mode (Gbps) | Bonded Mode (Gbps) | Channel Span | Non- bonded Mode (Gbps) | Bonded Mode (Gbps) | Channel Span |
| x1 ⁽³⁾ | 14.1 | _ | 6 | 12.5 | _ | 6 | 3.125 | _ | 3 |
| x6 ⁽³⁾ | _ | 14.1 | 6 | _ | 12.5 | 6 | _ | 3.125 | 6 |
| x6 PLL Feedback ⁽⁴⁾ | _ | 14.1 | Side- wide | _ | 12.5 | Side- wide | _ | _ | _ |
| xN (PCIe) | _ | 8.0 | 8 | _ | 5.0 | 8 | _ | _ | _ |
| xN (Native PHY IP) - | 8.0 | 8.0 | Up to 13 channels above and below PLL | 7.99 | 7.99 | Up to 13 channels above | 3.125 | 3.125 | Up to 13 channels above |
| | П | 8.01 to 9.8304 | Up to 7 channels above and below PLL | · 7.55 | 7.88 | and below PLL | 3.123 | 3.123 | and below PLL |

Notes to Table 24:

⁽¹⁾ Valid data rates below the maximum specified in this table depend on the reference clock frequency and the PLL counter settings. Check the MegaWizard message during the PHY IP instantiation.

⁽²⁾ ATX PLL is recommended at 8 Gbps and above data rates for improved jitter performance.

⁽³⁾ Channel span is within a transceiver bank.

⁽⁴⁾ Side-wide channel bonding is allowed up to the maximum supported by the PHY IP.

Page 28 Switching Characteristics

Table 27 shows the $\ensuremath{V_{OD}}$ settings for the GX channel.

Table 27. Typical V $_{\text{OD}}$ Setting for GX Channel, TX Termination = 100 Ω $^{(2)}$

| Symbol | V _{OD} Setting | V _{op} Value (mV) | V _{op} Setting | V _{op} Value (mV) |
|---------------------------------------|-------------------------|-------------------------------|-------------------------|-------------------------------|
| | 0 (1) | 0 | 32 | 640 |
| | 1 (1) | 20 | 33 | 660 |
| | 2 (1) | 40 | 34 | 680 |
| | 3 (1) | 60 | 35 | 700 |
| | 4 (1) | 80 | 36 | 720 |
| | 5 ⁽¹⁾ | 100 | 37 | 740 |
| | 6 | 120 | 38 | 760 |
| | 7 | 140 | 39 | 780 |
| | 8 | 160 | 40 | 800 |
| | 9 | 180 | 41 | 820 |
| | 10 | 200 | 42 | 840 |
| | 11 | 220 | 43 | 860 |
| | 12 | 240 | 44 | 880 |
| | 13 | 260 | 45 | 900 |
| | 14 | 280 | 46 | 920 |
| V op differential peak to peak | 15 | 300 | 47 | 940 |
| typical ⁽³⁾ | 16 | 320 | 48 | 960 |
| | 17 | 340 | 49 | 980 |
| | 18 | 360 | 50 | 1000 |
| | 19 | 380 | 51 | 1020 |
| | 20 | 400 | 52 | 1040 |
| | 21 | 420 | 53 | 1060 |
| | 22 | 440 | 54 | 1080 |
| | 23 | 460 | 55 | 1100 |
| | 24 | 480 | 56 | 1120 |
| | 25 | 500 | 57 | 1140 |
| | 26 | 520 | 58 | 1160 |
| | 27 | 540 | 59 | 1180 |
| | 28 | 560 | 60 | 1200 |
| | 29 | 580 | 61 | 1220 |
| | 30 | 600 | 62 | 1240 |
| | 31 | 620 | 63 | 1260 |

Note to Table 27:

- (1) If TX termination resistance = 100Ω , this VOD setting is illegal.
- (2) The tolerance is +/-20% for all VOD settings except for settings 2 and below.
- (3) Refer to Figure 2.

Figure 2 shows the differential transmitter output waveform.

Figure 2. Differential Transmitter Output Waveform

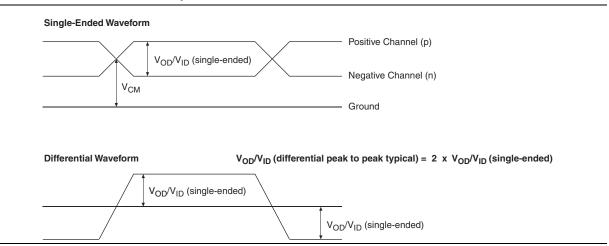


Figure 3 shows the Stratix V AC gain curves for GX channels.

Figure 3. AC Gain Curves for GX Channels (full bandwidth)



Stratix V GT devices contain both GX and GT channels. All transceiver specifications for the GX channels not listed in Table 28 are the same as those listed in Table 23.

Table 28 lists the Stratix V GT transceiver specifications.

Page 32 Switching Characteristics

Table 28. Transceiver Specifications for Stratix V GT Devices (Part 3 of 5) $^{(1)}$

| Symbol/ | Conditions | | Transceiver Speed Grade | | | Transceive peed Grade | | Unit |
|---|----------------------------------|----------------------|----------------------------|--------|-----|--------------------------|--------|-------|
| Description | | Min | Тур | Max | Min | Тур | Max | |
| Differential on-chip termination resistors (7) | GT channels | _ | 100 | _ | _ | 100 | _ | Ω |
| | 85-Ω setting | _ | 85 ± 30% | _ | _ | 85 ± 30% | _ | Ω |
| Differential on-chip termination resistors | 100-Ω setting | _ | 100 ± 30% | _ | _ | 100 ± 30% | _ | Ω |
| for GX channels (19) | 120-Ω setting | _ | 120 ± 30% | _ | _ | 120 ± 30% | _ | Ω |
| V (AC coupled) | 150-Ω setting | _ | 150 ± 30% | _ | _ | 150 ± 30% | _ | Ω |
| V _{ICM} (AC coupled) | GT channels | _ | 650 | _ | _ | 650 | _ | mV |
| | VCCR_GXB = 0.85 V or 0.9 V | _ | 600 | _ | _ | 600 | _ | mV |
| VICM (AC and DC coupled) for GX Channels | VCCR_GXB = 1.0 V full bandwidth | _ | 700 | _ | _ | 700 | _ | mV |
| | VCCR_GXB = 1.0 V half bandwidth | _ | 750 | _ | _ | 750 | _ | mV |
| t _{LTR} ⁽⁹⁾ | _ | _ | _ | 10 | _ | _ | 10 | μs |
| t _{LTD} ⁽¹⁰⁾ | _ | 4 | _ | _ | 4 | _ | _ | μs |
| t _{LTD_manual} (11) | | 4 | _ | _ | 4 | _ | _ | μs |
| t _{LTR_LTD_manual} (12) | | 15 | _ | _ | 15 | _ | _ | μs |
| Run Length | GT channels | _ | _ | 72 | _ | _ | 72 | CID |
| nuii Leiigiii | GX channels | | | | (8) | | | |
| CDR PPM | GT channels | _ | _ | 1000 | _ | _ | 1000 | ± PPM |
| ODITITIVI | GX channels | | | | (8) | | | |
| Programmable | GT channels | _ | _ | 14 | _ | _ | 14 | dB |
| equalization (AC Gain) ⁽⁵⁾ | GX channels | | | | (8) | | | |
| Programmable | GT channels | _ | _ | 7.5 | _ | _ | 7.5 | dB |
| DC gain ⁽⁶⁾ | GX channels | | | | (8) | | | |
| Differential on-chip termination resistors ⁽⁷⁾ | GT channels | | 100 | _ | _ | 100 | _ | Ω |
| Transmitter | · ' | | • | | | • | • | |
| Supported I/O Standards | _ | 1.4-V and 1.5-V PCML | | | | | | |
| Data rate (Standard PCS) | GX channels | 600 | _ | 8500 | 600 | _ | 8500 | Mbps |
| Data rate (10G PCS) | GX channels | 600 | _ | 12,500 | 600 | | 12,500 | Mbps |

Page 34 Switching Characteristics

Table 28. Transceiver Specifications for Stratix V GT Devices (Part 5 of 5) (1)

| Symbol/ Description Conditio | | | Transceivei peed Grade | | T Sp | Unit | | |
|---------------------------------|---|-----|---------------------------|-----|---------|------|-----|----|
| | | Min | Тур | Max | Min | Тур | Max | |
| t _{pll_lock} (14) | _ | _ | _ | 10 | _ | _ | 10 | μs |

Notes to Table 28:

- (1) Speed grades shown refer to the PMA Speed Grade in the device ordering code. The maximum data rate could be restricted by the Core/PCS speed grade. Contact your Altera Sales Representative for the maximum data rate specifications in each speed grade combination offered. For more information about device ordering codes, refer to the *Stratix V Device Overview*.
- (2) The reference clock common mode voltage is equal to the VCCR_GXB power supply level.
- (3) The device cannot tolerate prolonged operation at this absolute maximum.
- (4) The differential eye opening specification at the receiver input pins assumes that receiver equalization is disabled. If you enable receiver equalization, the receiver circuitry can tolerate a lower minimum eye opening, depending on the equalization level.
- (5) Refer to Figure 5 for the GT channel AC gain curves. The total effective AC gain is the AC gain minus the DC gain.
- (6) Refer to Figure 6 for the GT channel DC gain curves.
- (7) CFP2 optical modules require the host interface to have the receiver data pins differentially terminated with 100 Ω. The internal OCT feature is available after the Stratix V FPGA configuration is completed. Altera recommends that FPGA configuration is completed before inserting the optical module. Otherwise, minimize unnecessary removal and insertion with unconfigured devices.
- (8) Specifications for this parameter are the same as for Stratix V GX and GS devices. See Table 23 for specifications.
- (9) t_{LTB} is the time required for the receive CDR to lock to the input reference clock frequency after coming out of reset.
- (10) tLTD is time required for the receiver CDR to start recovering valid data after the rx is lockedtodata signal goes high.
- (11) t_{LTD_manual} is the time required for the receiver CDR to start recovering valid data after the rx_is_lockedtodata signal goes high when the CDR is functioning in the manual mode.
- (12) t_{LTR_LTD_manual} is the time the receiver CDR must be kept in lock to reference (LTR) mode after the rx_is_lockedtoref signal goes high when the CDR is functioning in the manual mode.
- (13) tpll powerdown is the PLL powerdown minimum pulse width.
- (14) tpll lock is the time required for the transmitter CMU/ATX PLL to lock to the input reference clock frequency after coming out of reset.
- (15) To calculate the REFCLK rms phase jitter requirement for PCle at reference clock frequencies other than 100 MHz, use the following formula: REFCLK rms phase jitter at f(MHz) = REFCLK rms phase jitter at 100 MHz × 100/f.
- (16) The maximum peak to peak differential input voltage V_{ID} after device configuration is equal to 4 × (absolute V_{MAX} for receiver pin V_{ICM}).
- (17) For ES devices, RREF is 2000 Ω ±1%.
- (18) To calculate the REFCLK phase noise requirement at frequencies other than 622 MHz, use the following formula: REFCLK phase noise at f(MHz) = REFCLK phase noise at 622 MHz + 20*log(f/622).
- (19) SFP/+ optical modules require the host interface to have RD+/- differentially terminated with 100 Ω. The internal OCT feature is available after the Stratix V FPGA configuration is completed. Altera recommends that FPGA configuration is completed before inserting the optical module. Otherwise, minimize unnecessary removal and insertion with unconfigured devices.
- (20) Refer to Figure 4.
- (21) For oversampling design to support data rates less than the minimum specification, the CDR needs to be in LTR mode only.
- (22) This supply follows VCCR_GXB for both GX and GT channels.
- (23) When you use fPLL as a TXPLL of the transceiver.

Page 38 Switching Characteristics

- XFI
- ASI
- HiGig/HiGig+
- HiGig2/HiGig2+
- Serial Data Converter (SDC)
- GPON
- SDI
- SONET
- Fibre Channel (FC)
- PCIe
- QPI
- SFF-8431

Download the Stratix V Characterization Report Tool to view the characterization report summary for these protocols.

Core Performance Specifications

This section describes the clock tree, phase-locked loop (PLL), digital signal processing (DSP), memory blocks, configuration, and JTAG specifications.

Clock Tree Specifications

Table 30 lists the clock tree specifications for Stratix V devices.

Table 30. Clock Tree Performance for Stratix V Devices (1)

| | Performance | | | | | | | | |
|------------------------------|--------------------------|--------------------------|--------|------|--|--|--|--|--|
| Symbol | C1, C2, C2L, I2, and I2L | C3, I3, I3L, and I3YY | C4, I4 | Unit | | | | | |
| Global and Regional Clock | 717 | 650 | 580 | MHz | | | | | |
| Periphery Clock | 550 | 500 | 500 | MHz | | | | | |

Note to Table 30:

(1) The Stratix V ES devices are limited to 600 MHz core clock tree performance.

PLL Specifications

Table 31 lists the Stratix V PLL specifications when operating in both the commercial junction temperature range (0° to 85°C) and the industrial junction temperature range (-40° to 100° C).

Table 31. PLL Specifications for Stratix V Devices (Part 1 of 3)

| Symbol | Parameter | Min | Тур | Max | Unit |
|---------------------------------|--|-----|-----|--------------------|------|
| | Input clock frequency (C1, C2, C2L, I2, and I2L speed grades) | 5 | _ | 800 (1) | MHz |
| f _{IN} | Input clock frequency (C3, I3, I3L, and I3YY speed grades) | 5 | _ | 800 (1) | MHz |
| | Input clock frequency (C4, I4 speed grades) | 5 | _ | 650 ⁽¹⁾ | MHz |
| f _{INPFD} | Input frequency to the PFD | 5 | _ | 325 | MHz |
| FINPFD | Fractional Input clock frequency to the PFD | 50 | _ | 160 | MHz |
| | PLL VCO operating range (C1, C2, C2L, I2, I2L speed grades) | 600 | _ | 1600 | MHz |
| f _{vco} ⁽⁹⁾ | PLL VCO operating range (C3, I3, I3L, I3YY speed grades) | 600 | _ | 1600 | MHz |
| | PLL VCO operating range (C4, I4 speed grades) | 600 | _ | 1300 | MHz |
| EINDUTY | Input clock or external feedback clock input duty cycle | 40 | _ | 60 | % |
| | Output frequency for an internal global or regional clock (C1, C2, C2L, I2, I2L speed grades) | _ | _ | 717 (2) | MHz |
| f _{OUT} | Output frequency for an internal global or regional clock (C3, I3, I3L speed grades) | _ | _ | 650 ⁽²⁾ | MHz |
| | Output frequency for an internal global or regional clock (C4, I4 speed grades) | _ | _ | 580 ⁽²⁾ | MHz |
| | Output frequency for an external clock output (C1, C2, C2L, I2, I2L speed grades) | _ | _ | 800 (2) | MHz |
| f _{OUT_EXT} | Output frequency for an external clock output (C3, I3, I3L speed grades) | _ | _ | 667 (2) | MHz |
| | Output frequency for an external clock output (C4, I4 speed grades) | _ | _ | 553 ⁽²⁾ | MHz |
| t _{оитриту} | Duty cycle for a dedicated external clock output (when set to 50%) | 45 | 50 | 55 | % |
| FCOMP | External feedback clock compensation time | _ | _ | 10 | ns |
| f _{DYCONFIGCLK} | Dynamic Configuration Clock used for mgmt_clk and scanclk | _ | _ | 100 | MHz |
| Lock | Time required to lock from the end-of-device configuration or deassertion of areset | _ | _ | 1 | ms |
| DLOCK | Time required to lock dynamically (after switchover or reconfiguring any non-post-scale counters/delays) | | _ | 1 | ms |
| | PLL closed-loop low bandwidth | | 0.3 | | MHz |
| : CLBW | PLL closed-loop medium bandwidth | | 1.5 | | MHz |
| | PLL closed-loop high bandwidth (7) | _ | 4 | _ | MHz |
| PLL_PSERR | Accuracy of PLL phase shift | | _ | ±50 | ps |
| ARESET | Minimum pulse width on the areset signal | 10 | _ | _ | ns |

Page 40 Switching Characteristics

Table 31. PLL Specifications for Stratix V Devices (Part 2 of 3)

| Symbol | Parameter | Min | Тур | Max | Unit |
|--|---|------|---------|--|-----------|
| → (3) (4) | Input clock cycle-to-cycle jitter (f _{REF} ≥ 100 MHz) | _ | _ | 0.15 | UI (p-p) |
| t _{INCCJ} (3), (4) | Input clock cycle-to-cycle jitter (f _{REF} < 100 MHz) | -750 | | +750 | ps (p-p) |
| + (5) | Period Jitter for dedicated clock output ($f_{OUT} \ge 100 \text{ MHz}$) | _ | _ | 175 ⁽¹⁾ | ps (p-p) |
| t _{OUTPJ_DC} (5) | Period Jitter for dedicated clock output (f _{OUT} < 100 MHz) | _ | _ | 17.5 ⁽¹⁾ | mUI (p-p) |
| + (5) | Period Jitter for dedicated clock output in fractional PLL ($f_{OUT} \ge 100 \text{ MHz}$) | _ | _ | 250 ⁽¹¹⁾ , 175 ⁽¹²⁾ | ps (p-p) |
| t _{FOUTPJ_DC} (5) | Period Jitter for dedicated clock output in fractional PLL (f _{OUT} < 100 MHz) | _ | _ | 25 ⁽¹¹⁾ , 17.5 ⁽¹²⁾ | mUI (p-p) |
| + (5) | Cycle-to-Cycle Jitter for a dedicated clock output $(f_{OUT} \ge 100 \text{ MHz})$ | _ | _ | 175 | ps (p-p) |
| t _{outccj_dc} (5) | Cycle-to-Cycle Jitter for a dedicated clock output (f _{OUT} < 100 MHz) | _ | _ | 17.5 | mUI (p-p) |
| + (5) | Cycle-to-cycle Jitter for a dedicated clock output in fractional PLL ($f_{OUT} \ge 100$ MHz) | _ | _ | 250 ⁽¹¹⁾ , 175 ⁽¹²⁾ | ps (p-p) |
| t _{FOUTCCJ_DC} ⁽⁵⁾ | Cycle-to-cycle Jitter for a dedicated clock output in fractional PLL (f _{OUT} < 100 MHz)+ | _ | _ | 25 ⁽¹¹⁾ , 17.5 ⁽¹²⁾ | mUI (p-p) |
| t _{OUTPJ_IO} (5), | Period Jitter for a clock output on a regular I/O in integer PLL ($f_{OUT} \ge 100 \text{ MHz}$) | _ | _ | 600 | ps (p-p) |
| (8) | Period Jitter for a clock output on a regular I/O (f _{OUT} < 100 MHz) | _ | _ | 60 | mUI (p-p) |
| t _{FOUTPJ 10} (5), | Period Jitter for a clock output on a regular I/O in fractional PLL ($f_{OUT} \ge 100 \text{ MHz}$) | _ | _ | 600 (10) | ps (p-p) |
| (8), (11) | Period Jitter for a clock output on a regular I/O in fractional PLL (f_{OUT} < 100 MHz) | _ | _ | 60 (10) | mUI (p-p) |
| t _{outccj_10} (5), | Cycle-to-cycle Jitter for a clock output on a regular I/O in integer PLL ($f_{OUT} \ge 100$ MHz) | _ | _ | 600 | ps (p-p) |
| (8) | Cycle-to-cycle Jitter for a clock output on a regular I/O in integer PLL (f_{OUT} < 100 MHz) | _ | _ | 60 (10) | mUI (p-p) |
| t _{FOUTCCJ_IO} | Cycle-to-cycle Jitter for a clock output on a regular I/O in fractional PLL ($f_{OUT} \ge 100$ MHz) | _ | _ | 600 (10) | ps (p-p) |
| (8), (11) | Cycle-to-cycle Jitter for a clock output on a regular I/O in fractional PLL (f_{OUT} < 100 MHz) | _ | _ | 60 | mUI (p-p) |
| t _{CASC_OUTPJ_DC} | Period Jitter for a dedicated clock output in cascaded PLLs ($f_{OUT} \geq 100 \text{ MHz}$) | _ | _ | 175 | ps (p-p) |
| (5), (6) | Period Jitter for a dedicated clock output in cascaded PLLs (f _{OUT} < 100 MHz) | _ | _ | 17.5 | mUI (p-p) |
| f _{DRIFT} | Frequency drift after PFDENA is disabled for a duration of 100 µs | _ | _ | ±10 | % |
| dK _{BIT} | Bit number of Delta Sigma Modulator (DSM) | 8 | 24 | 32 | Bits |
| k _{VALUE} | Numerator of Fraction | 128 | 8388608 | 2147483648 | _ |

Table 31. PLL Specifications for Stratix V Devices (Part 3 of 3)

| | Symbol | Parameter | Min | Тур | Max | Unit |
|---|--------|--|--------|------|-------|------|
| f | RES | Resolution of VCO frequency (f _{INPFD} = 100 MHz) | 390625 | 5.96 | 0.023 | Hz |

Notes to Table 31:

- (1) This specification is limited in the Quartus II software by the I/O maximum frequency. The maximum I/O frequency is different for each I/O standard.
- (2) This specification is limited by the lower of the two: I/O f_{MAX} or f_{OUT} of the PLL.
- (3) A high input jitter directly affects the PLL output jitter. To have low PLL output clock jitter, you must provide a clean clock source < 120 ps.
- (4) f_{REF} is fIN/N when N = 1.
- (5) Peak-to-peak jitter with a probability level of 10⁻¹² (14 sigma, 99.9999999974404% confidence level). The output jitter specification applies to the intrinsic jitter of the PLL, when an input jitter of 30 ps is applied. The external memory interface clock output jitter specifications use a different measurement method and are available in Table 44 on page 52.
- (6) The cascaded PLL specification is only applicable with the following condition:
 - a. Upstream PLL: 0.59Mhz \le Upstream PLL BW < 1 MHz
 - b. Downstream PLL: Downstream PLL BW > 2 MHz
- (7) High bandwidth PLL settings are not supported in external feedback mode.
- (8) The external memory interface clock output jitter specifications use a different measurement method, which is available in Table 42 on page 50.
- (9) The VCO frequency reported by the Quartus II software in the PLL Usage Summary section of the compilation report takes into consideration the VCO post-scale counter K value. Therefore, if the counter K has a value of 2, the frequency reported can be lower than the f_{VCO} specification.
- (10) This specification only covers fractional PLL for low bandwidth. The f_{VCO} for fractional value range 0.05 0.95 must be \geq 1000 MHz, while f_{VCO} for fractional value range 0.20 0.80 must be \geq 1200 MHz.
- (11) This specification only covered fractional PLL for low bandwidth. The f_{VCO} for fractional value range 0.05-0.95 must be ≥ 1000 MHz.
- (12) This specification only covered fractional PLL for low bandwidth. The f_{VCO} for fractional value range 0.20-0.80 must be ≥ 1200 MHz.

DSP Block Specifications

Table 32 lists the Stratix V DSP block performance specifications.

Table 32. Block Performance Specifications for Stratix V DSP Devices (Part 1 of 2)

| Mode | C1 | C2, C2L | 12, 12L | C3 | 13, 13L, 13YY | C4 | 14 | Unit |
|--|-----|---------|------------|------|------------------|-----|-----|------|
| Modes using one DSP | | | | | | | | |
| Three 9 x 9 | 600 | 600 | 600 | 480 | 480 | 420 | 420 | MHz |
| One 18 x 18 | 600 | 600 | 600 | 480 | 480 | 420 | 400 | MHz |
| Two partial 18 x 18 (or 16 x 16) | 600 | 600 | 600 | 480 | 480 | 420 | 400 | MHz |
| One 27 x 27 | 500 | 500 | 500 | 400 | 400 | 350 | 350 | MHz |
| One 36 x 18 | 500 | 500 | 500 | 400 | 400 | 350 | 350 | MHz |
| One sum of two 18 x 18(One sum of 2 16 x 16) | 500 | 500 | 500 | 400 | 400 | 350 | 350 | MHz |
| One sum of square | 500 | 500 | 500 | 400 | 400 | 350 | 350 | MHz |
| One 18 x 18 plus 36 (a x b) + c | 500 | 500 | 500 | 400 | 400 | 350 | 350 | MHz |
| | | Modes u | sing two I |)SPs | | | | |
| Three 18 x 18 | 500 | 500 | 500 | 400 | 400 | 350 | 350 | MHz |
| One sum of four 18 x 18 | 475 | 475 | 475 | 380 | 380 | 300 | 300 | MHz |
| One sum of two 27 x 27 | 465 | 465 | 450 | 380 | 380 | 300 | 290 | MHz |
| One sum of two 36 x 18 | 475 | 475 | 475 | 380 | 380 | 300 | 300 | MHz |
| One complex 18 x 18 | 500 | 500 | 500 | 400 | 400 | 350 | 350 | MHz |
| One 36 x 36 | 475 | 475 | 475 | 380 | 380 | 300 | 300 | MHz |

Table 36. High-Speed I/O Specifications for Stratix V Devices (1), (2) (Part 4 of 4)

| Cumbal | Conditions – | | C 1 | | C2, C2L, I2, I2L | | C3, I3, I3L, I3YY | | | C4,14 | | | Unit | |
|-------------------------------|--|-----|------------|-----------|------------------|-----|-------------------|-----|-----|-----------|-----|-----|-----------|----------|
| Symbol | | | Тур | Max | Min | Тур | Max | Min | Тур | Max | Min | Тур | Max | Ullit |
| | SERDES factor J = 3 to 10 | (6) | _ | (8) | (6) | | (8) | (6) | | (8) | (6) | _ | (8) | Mbps |
| f _{HSDR} (data rate) | SERDES factor J = 2, uses DDR Registers | (6) | | (7) | (6) | | (7) | (6) | | (7) | (6) | | (7) | Mbps |
| | SERDES factor J = 1, uses SDR Register | | _ | (7) | (6) | _ | (7) | (6) | _ | (7) | (6) | _ | (7) | Mbps |
| DPA Mode | DPA Mode | | | | | | | | | | | | | |
| DPA run length | _ | | _ | 1000 0 | _ | _ | 1000 0 | _ | _ | 1000 0 | _ | _ | 1000 0 | UI |
| Soft CDR mode | Soft CDR mode | | | | | | | | | | | | | |
| Soft-CDR PPM tolerance | _ | _ | _ | 300 | _ | _ | 300 | _ | _ | 300 | _ | _ | 300 | ± PPM |
| Non DPA Mode | Non DPA Mode | | | | | | | | | | | | | |
| Sampling Window | _ | _ | _ | 300 | _ | | 300 | _ | | 300 | _ | _ | 300 | ps |

Notes to Table 36:

- (1) When J = 3 to 10, use the serializer/deserializer (SERDES) block.
- (2) When J = 1 or 2, bypass the SERDES block.
- (3) This only applies to DPA and soft-CDR modes.
- (4) Clock Boost Factor (W) is the ratio between the input data rate to the input clock rate.
- (5) This is achieved by using the **LVDS** clock network.
- (6) The minimum specification depends on the clock source (for example, the PLL and clock pin) and the clock routing resource (global, regional, or local) that you use. The I/O differential buffer and input register do not have a minimum toggle rate.
- (7) The maximum ideal frequency is the SERDES factor (J) x the PLL maximum output frequency (fOUT) provided you can close the design timing and the signal integrity simulation is clean.
- (8) You can estimate the achievable maximum data rate for non-DPA mode by performing link timing closure analysis. You must consider the board skew margin, transmitter delay margin, and receiver sampling margin to determine the maximum data rate supported.
- (9) If the receiver with DPA enabled and transmitter are using shared PLLs, the minimum data rate is 150 Mbps.
- (10) You must calculate the leftover timing margin in the receiver by performing link timing closure analysis. You must consider the board skew margin, transmitter channel-to-channel skew, and receiver sampling margin to determine leftover timing margin.
- (11) The F_{MAX} specification is based on the fast clock used for serial data. The interface F_{MAX} is also dependent on the parallel clock domain which is design-dependent and requires timing analysis.
- (12) Stratix V RX LVDS will need DPA. For Stratix V TX LVDS, the receiver side component must have DPA.
- (13) Stratix V LVDS serialization and de-serialization factor needs to be x4 and above.
- (14) Requires package skew compensation with PCB trace length.
- (15) Do not mix single-ended I/O buffer within LVDS I/O bank.
- (16) Chip-to-chip communication only with a maximum load of 5 pF.
- (17) When using True LVDS RX channels for emulated LVDS TX channel, only serialization factors 1 and 2 are supported.

Configuration Specification Page 57

FPP Configuration Timing when DCLK-to-DATA [] = 1

Figure 12 shows the timing waveform for FPP configuration when using a MAX II or MAX V device as an external host. This waveform shows timing when the DCLK-to-DATA[] ratio is 1.

Figure 12. FPP Configuration Timing Waveform When the DCLK-to-DATA[] Ratio is 1 (1), (2)



Notes to Figure 12:

- (1) Use this timing waveform when the DCLK-to-DATA[] ratio is 1.
- (2) The beginning of this waveform shows the device in user mode. In user mode, nCONFIG, nSTATUS, and CONF_DONE are at logic-high levels. When nCONFIG is pulled low, a reconfiguration cycle begins.
- (3) After power-up, the Stratix V device holds nSTATUS low for the time of the POR delay.
- (4) After power-up, before and during configuration, CONF DONE is low.
- (5) Do not leave DCLK floating after configuration. DCLK is ignored after configuration is complete. It can toggle high or low if required.
- (6) For FPP ×16, use DATA [15..0]. For FPP ×8, use DATA [7..0]. DATA [31..0] are available as a user I/O pin after configuration. The state of this pin depends on the dual-purpose pin settings.
- (7) To ensure a successful configuration, send the entire configuration data to the Stratix V device. CONF_DONE is released high when the Stratix V device receives all the configuration data successfully. After CONF_DONE goes high, send two additional falling edges on DCLK to begin initialization and enter user mode.
- (8) After the option bit to enable the <code>INIT_DONE</code> pin is configured into the device, the <code>INIT_DONE</code> goes low.

Glossary Page 65

Table 58. IOE Programmable Delay for Stratix V Devices (Part 2 of 2)

| Parameter | Available | Min | Fast | Fast Model | | | Slow Model | | | | | | | |
|-----------|-----------|------------|------------|------------|-------|-------|------------|-------|-------|-------------|-------|------|--|--|
| (1) | Settings | Offset (2) | Industrial | Commercial | C1 | C2 | C3 | C4 | 12 | 13, 13YY | 14 | Unit | | |
| D3 | 8 | 0 | 1.587 | 1.699 | 2.793 | 2.793 | 2.992 | 3.192 | 2.811 | 3.047 | 3.257 | ns | | |
| D4 | 64 | 0 | 0.464 | 0.492 | 0.838 | 0.838 | 0.924 | 1.011 | 0.843 | 0.920 | 1.006 | ns | | |
| D5 | 64 | 0 | 0.464 | 0.493 | 0.838 | 0.838 | 0.924 | 1.011 | 0.844 | 0.921 | 1.006 | ns | | |
| D6 | 32 | 0 | 0.229 | 0.244 | 0.415 | 0.415 | 0.458 | 0.503 | 0.418 | 0.456 | 0.499 | ns | | |

Notes to Table 58:

- (1) You can set this value in the Quartus II software by selecting D1, D2, D3, D5, and D6 in the Assignment Name column of Assignment Editor.
- (2) Minimum offset does not include the intrinsic delay.

Programmable Output Buffer Delay

Table 59 lists the delay chain settings that control the rising and falling edge delays of the output buffer. The default delay is 0 ps.

Table 59. Programmable Output Buffer Delay for Stratix V Devices (1)

| Symbol | Parameter | Typical | Unit |
|---------------------|----------------------------|-------------|------|
| | | 0 (default) | ps |
| D _{OUTBUF} | Rising and/or falling edge | | ps |
| | delay | 50 | ps |
| | | 75 | ps |

Note to Table 59:

Glossary

Table 60 lists the glossary for this chapter.

Table 60. Glossary (Part 1 of 4)

| Letter | Subject | Definitions |
|--------|----------------------|---|
| Α | | |
| В | _ | _ |
| С | | |
| D | _ | _ |
| E | _ | |
| | f _{HSCLK} | Left and right PLL input clock frequency. |
| F | f _{HSDR} | High-speed I/O block—Maximum and minimum LVDS data transfer rate (f _{HSDR} = 1/TUI), non-DPA. |
| | f _{HSDRDPA} | High-speed I/O block—Maximum and minimum LVDS data transfer rate (f _{HSDRDPA} = 1/TUI), DPA. |

⁽¹⁾ You can set the programmable output buffer delay in the Quartus II software by setting the Output Buffer Delay Control assignment to either positive, negative, or both edges, with the specific values stated here (in ps) for the Output Buffer Delay assignment.